













































































## Why Measurement-Based Modeling?

- Analytical model may differ from reality:
  - Accuracy and assumptions of the analytical tool
  - Material properties may not be available
  - Geometries may not be available
  - Component manufacturing tolerances
- Accurate measurement is the true representation of reality
- Analytical models must be validated with measurement
- Accurate models achieved through prototype characterization

The Interconnect Modeling Company™ 🕵 🔲 🛛 🗛





































IConnect Short Interconnect Modeling							
Techn	iques f	pr Vari		kages			
	Model	modeling	modeling				
	required	method	method				
	С	Lumped					
SOIC		Adjacent-	Lumped				
	L	opposite					
	С	Lumped					
TSOP		Adjacent-	Lumped				
	L	opposite					
DCA.	Distributed,	Impedance	Even-odd				
PGA	coupled	profile	impedance				
OFR	Distributed-	Even-odd	Lumped,				
QFP	coupled	impedance	adjacent-opp.				
Small BGA,	Distributed-	Even-odd	Lumped,				
LGA	coupled	impedance	adjacent-opp.				
Large BGA,	Distributed-	Impedance	Even-odd				
LGA	coupled	profile	impedance				
МСМ	Distributed-	Impedance	Even-odd				
	coupled	profile	impedance				
	С	Lumped					
CSP		Adjacent-	Lumped				
	L	opposite					
	The I	nterconnect Mo	deling Company <sup>TI</sup>				





































































	Connect Failure Analysis TDR Differences from SAM and X-Ray							
		TDR	SAM	X-ray				
	Stimulus type	Electrical	Acoustic	X-ray				
	Stimulus delivery medium	Electrical wires	Water	Air				
	Direct contact required?	Yes, signal and ground	No	No				
	Output presented for analysis	Package trace reflection profile	Optical image	Optical image				
	Ability to locate failures between package layers	Good	Poor	Poor				
The Interconnect Modeling Company <sup>TM</sup>								

























IConnect Short Failure Analysis										
Plane-to-Plane Shorts TV Results										
	3"		-							
				<b>_</b> _	Physical	expect	tations			
Vias to bottom plane			3/8		Left	Center	Right			
C	1		ο	(3	Тор	X	2	6		
eft probe point Center probe point			5m	S Center	1	4	7			
Detter center probe point			E E	Bottom	3	5	8			
Image: Description of the second										
	Left	Center	Right			Left	Center	Right		
Тор	X	4	5		Тор	X	3	4		
Center	1	3	7		Center	1	5	7		
Bottom	2	6	8		Bottom	6	2	8		
The Interconnect Modeling Company™										

















































